



ATP302

P-Channel Power MOSFET -60V, -70A, 13mΩ, ATPAK

ON Semiconductor®
<http://onsemi.com>

Features

- ON-resistance $R_{DS(on)1}=10\text{m}\Omega$ (typ.)
- 4.5V drive
- Input capacitance $C_{iss}=5400\text{pF}$ (typ.)
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-60	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-70	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-280	A
Allowable Power Dissipation	P_D	$T_c=25^\circ\text{C}$	70	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$
Avalanche Energy (Single Pulse) *1	E_{AS}		197	mJ
Avalanche Current *2	I_{AV}		-42	A

 Note : *1 $V_{DD}=-36\text{V}$, $L=100\mu\text{H}$, $I_{AV}=-42\text{A}$

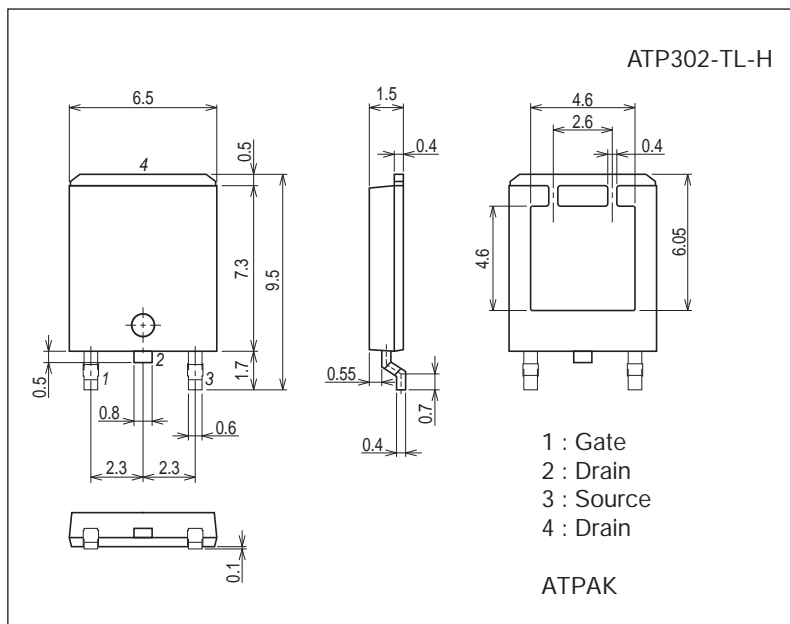
 *2 $L \leq 100\mu\text{H}$, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

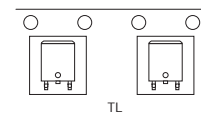
7057-001



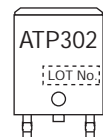
Product & Package Information

- Package : ATPAK
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

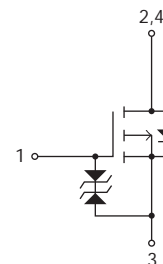
Packing Type: TL



Marking



Electrical Connection

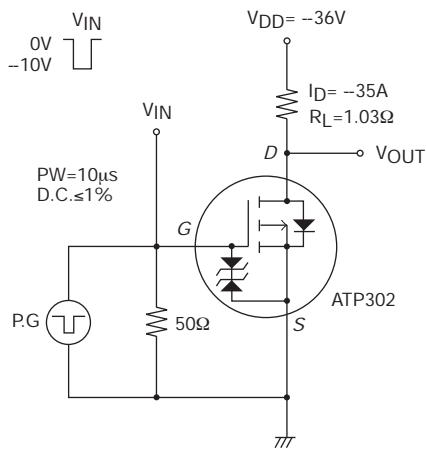


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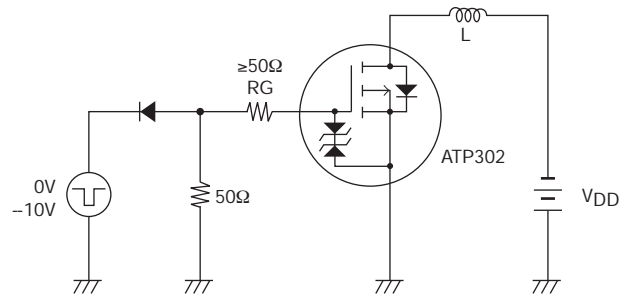
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1mA, V_{GS} = 0V$	-60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60V, V_{GS} = 0V$			-10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 16V, V_{DS} = 0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10V, I_D = -1mA$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10V, I_D = -35A$		75		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -35A, V_{GS} = -10V$		10	13	$m\Omega$
	$R_{DS(on)2}$	$I_D = -35A, V_{GS} = -4.5V$		13	18	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS} = -20V, f = 1MHz$		5400		pF
Output Capacitance	C_{oss}			500		pF
Reverse Transfer Capacitance	C_{rss}			370		pF
Turn-ON Delay Time	$t_{d(on)}$		See specified Test Circuit.		35	
Rise Time	t_r			430		ns
Turn-OFF Delay Time	$t_{d(off)}$			420		ns
Fall Time	t_f			500		ns
Total Gate Charge	Q_g	$V_{DS} = -36V, V_{GS} = -10V, I_D = -70A$			115	
Gate-to-Source Charge	Q_{gs}			20		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			25		nC
Diode Forward Voltage	V_{SD}	$I_S = -70A, V_{GS} = 0V$		-1.0	-1.5	V

Switching Time Test Circuit

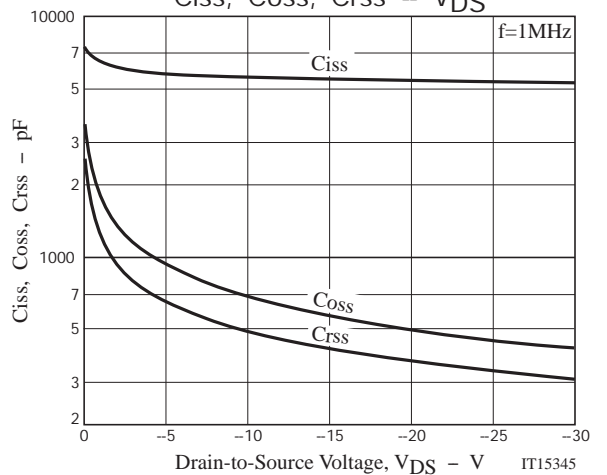
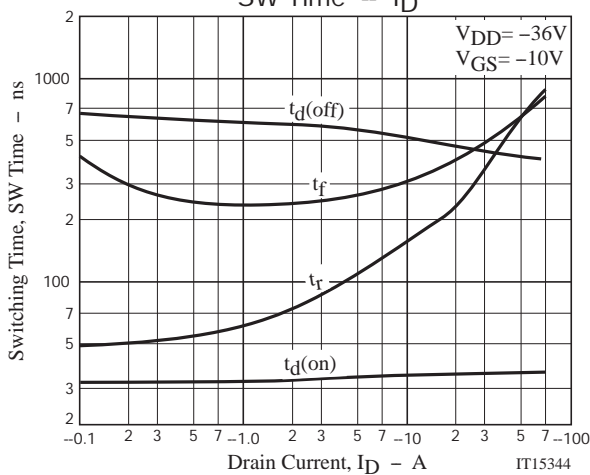
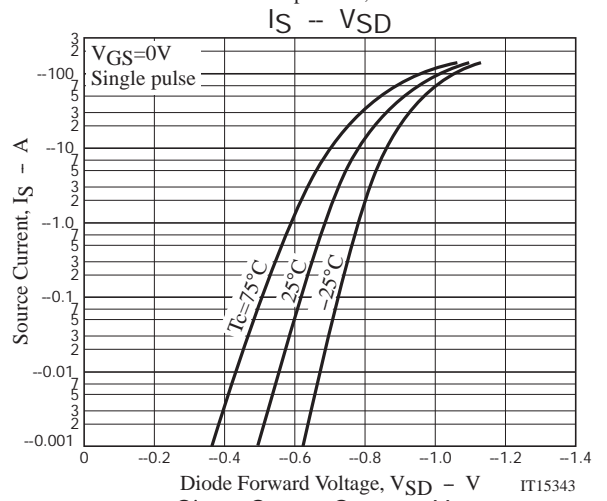
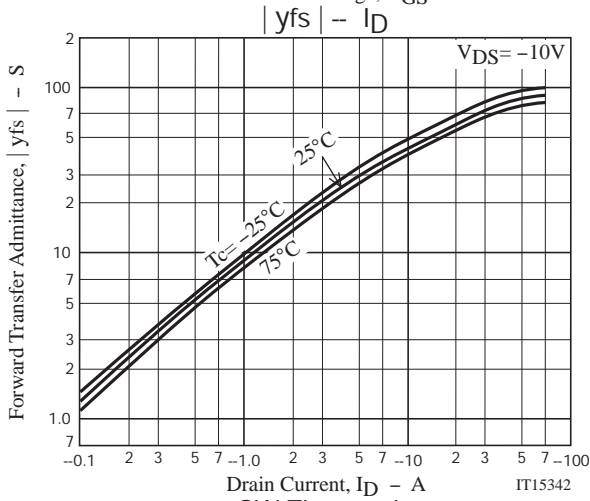
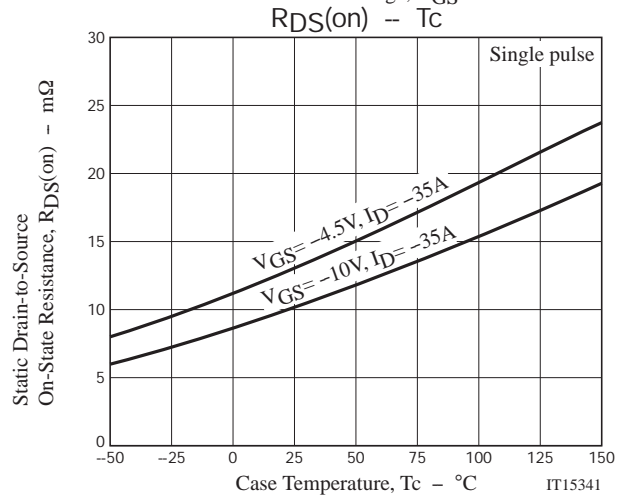
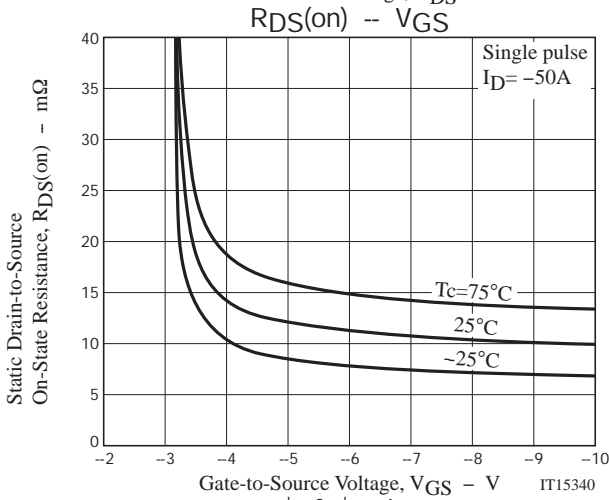
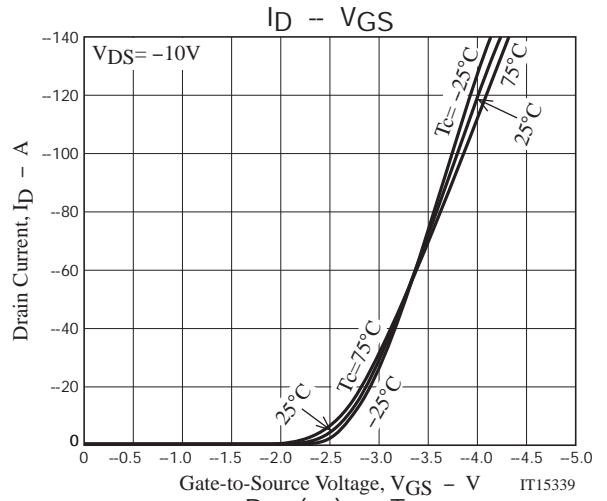
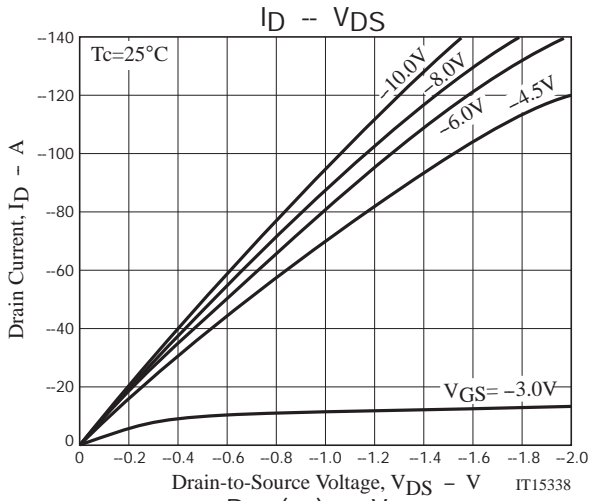


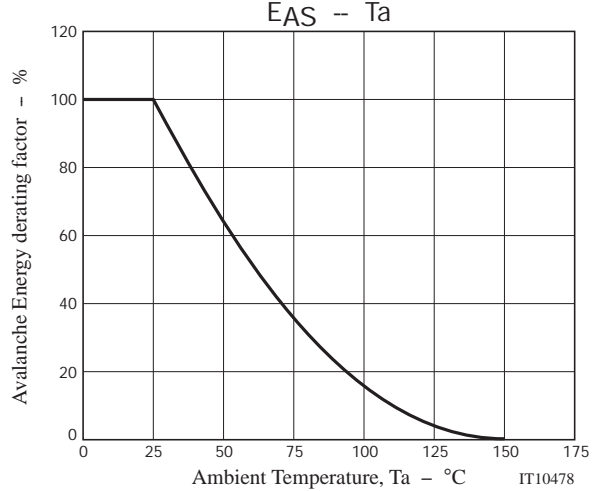
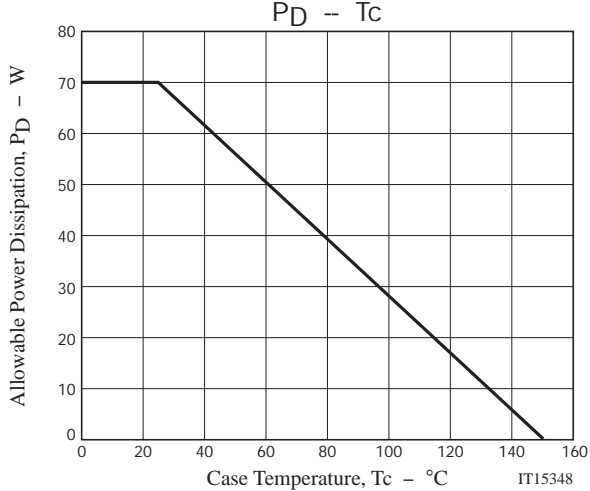
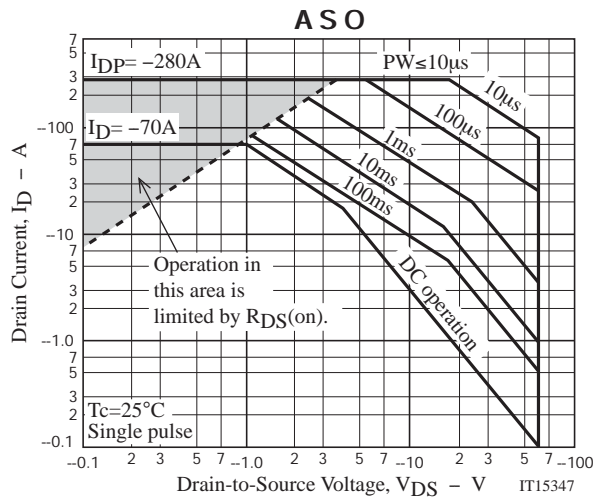
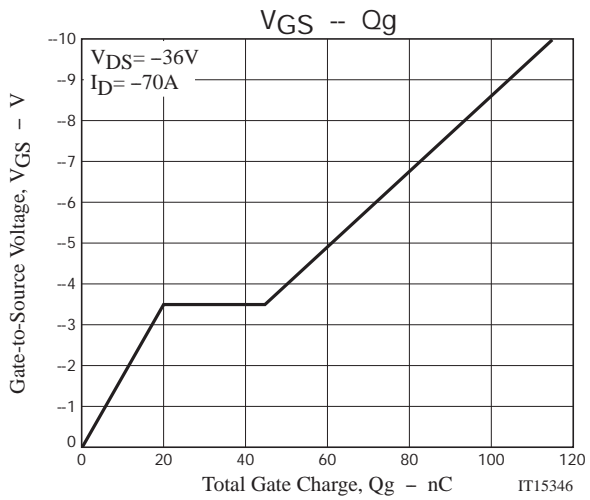
Avalanche Resistance Test Circuit



Ordering Information

Device	Package	Shipping	memo
ATP302-TL-H	ATPAK	3,000pcs./reel	Pb Free and Halogen Free





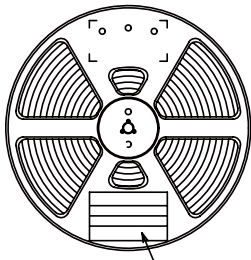
Taping Specification

ATP302-TL-H

1. Packing Format (TL)

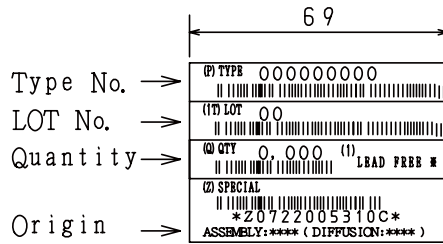
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	INNER BOX SD-C-18	OUTER BOX SD-A-18
ATPAK	ATP	3,000	3,000	15,000	1 reels contained Dimensions:mm (external) 340×340×28	5 inner boxes contained Dimensions:mm (external) 355×355×165

Packing method



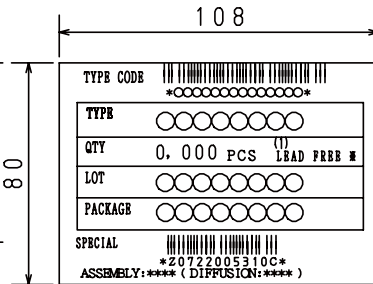
Reel label

Reel label, Inner box label
(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



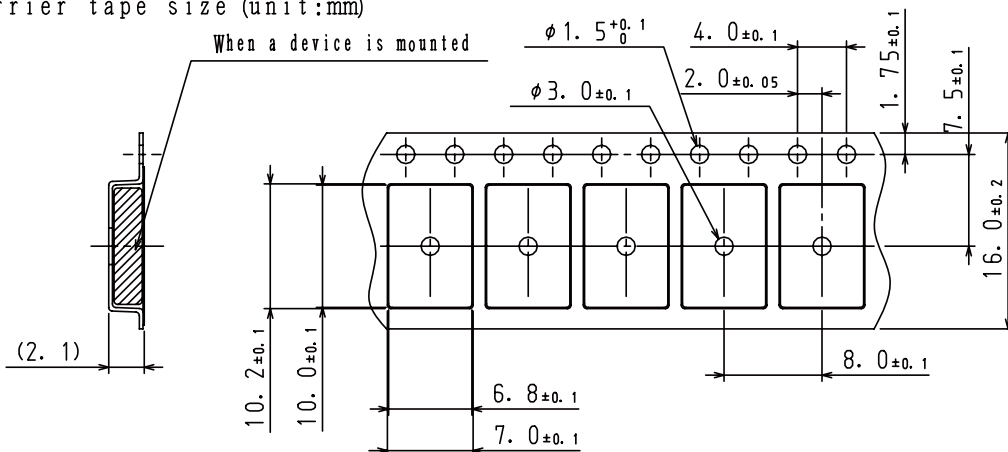
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

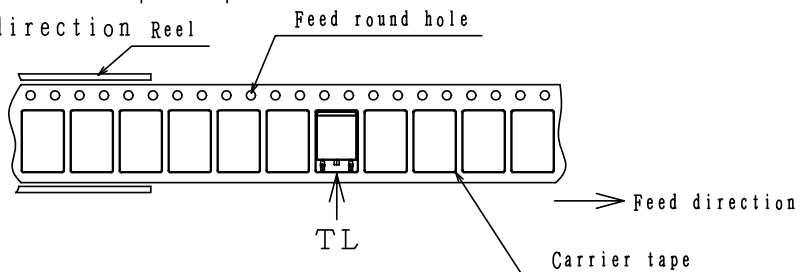
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction Reel

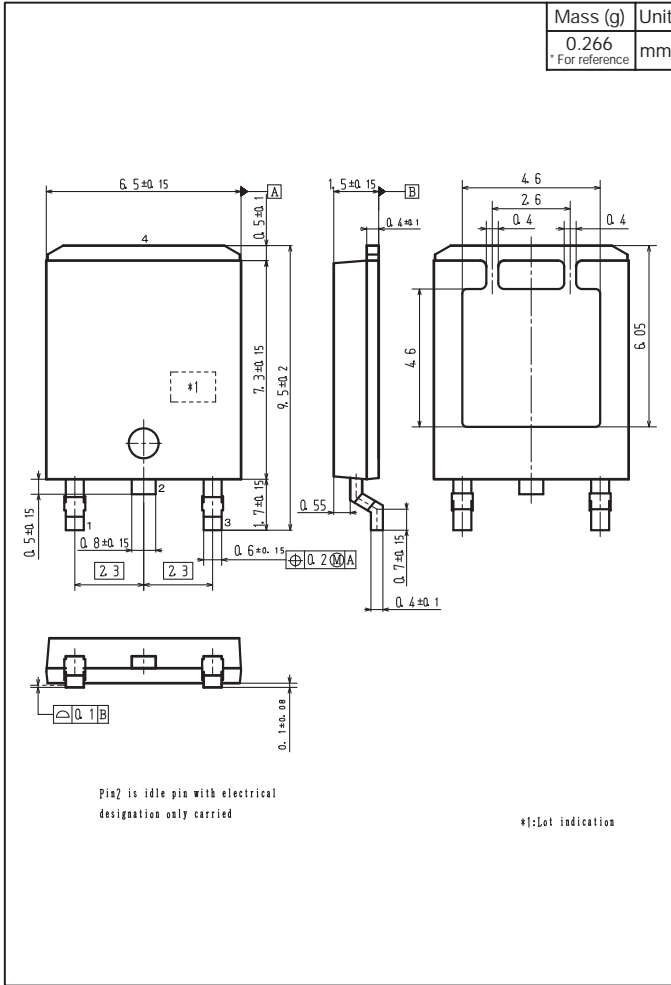


The one electrode terminals on feed hole side...TL

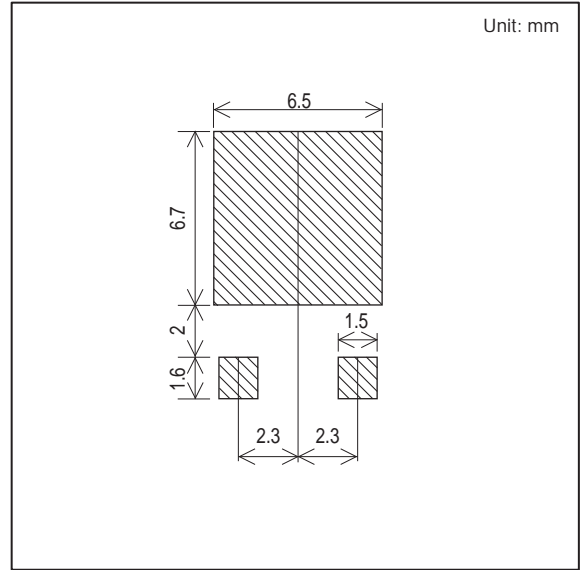
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Outline Drawing

ATP302-TL-H



Land Pattern Example



Note on usage : Since the ATP302 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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